DATA SHEET



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VISIBLE LIGHT DETECTOR WITH ANALOG & DIGITAL OUTPUTS 413101

DESCRIPTION

The 413101 is a low cost 4-pin visible light sensor, with a current output which is directly proportional to the light level. It has a built in optical filter to provide a response which is close to the human eye, or "photopic". It also has a digital output to provide on/off switching, with hysteresis to prevent flicker.

The output current can be converted to a voltage by connecting it in series with a resistor. The dynamic range is determined by the external resistor and power supply (e.g. 10K and 5V gives a range of 0 to over 250 Lux, but can be up to 1000 lux with a 1K resistor). The internal dark current cancellation enables high accuracy over the full temperature range, even at low light levels.

FEATURES

- Near human eye photopic response
- High IR rejection integrated optical filter
- Current output highly linear vs light level
- 1µA per lux current output
- External resistor sets linear lux range
- Temperature stable
- Integrated high gain photo-current amplifier
- Dark-current cancellation
- Digital output for on/off switching
- Hysteresis to prevent flicker close to switching threshold

APPLICATIONS

- Dawn/dusk sensing
- Security lighting
- Night-lights
- LCD backlight control

1.0 Basic application & test circuit



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2.0 FUNCTIONAL DESCRIPTION

Fig B Light falling on the 413101 is converted to current by the photodiode PD1.



PD2 is also a photodiode but it is covered by a metal layer so that it will not respond to light. At normal temperatures the dark current is very low, however at high temperatures without the dark current cancelling circuit it would become a significant source of error especially at low light levels. The dark current from PD2 is subtracted from the dark current and photo-current of PD1, the resultant current is multiplied by a linear high gain current amplifier and the multiplied current is available as source current from the ADJ pin. The photodiodes are covered by a multi-layer optical filter, which removes the IR light. With this optical filter the 413101 has an approximately "eye like" or photopic spectral response.

The primary function of the 413101 is to convert light to an output current at ADJ pin. The source current from the ADJ pin is proportional to the illumination on the device, at approximately 1 μ A per Lux. The 413101 has additional circuits to provide a digital ON/OFF output at the DIG_OUT pin in response to the voltage at the ADJ pin. The current out of the ADJ pin will normally be converted to a voltage by a resistor between ADJ and ground. A 10K resistor would provide a 10mV/lux output voltage at the ADJ pin. The internal resistor chain sets threshold voltages at the inputs of the comparators COMP1 and COMP2. The positive input of COMP1 is set to 0.15*V_{DD} and the negative input of COMP2 to 0.11* V_{DD}. When the voltage on the ADJ pin is less than 0.11*V_{DD} the flip-flop (U1/U2) is set and the DIG_OUT pin is switched high. When the voltage on the ADJ pin is higher than 0.15* V_{DD}, the flip-flop is reset and the DIG_OUT pin is switched low. This "hysteresis" prevents flickering of lamps or chattering of relays when the light level at the sensor is close to the switching threshold.

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3.0 ABSOLUTE MAXIMUM RATINGS

PARAMETER	RATING	UNITS
Supply input voltage	-0.3 to 10	V
Supply current	Internally limited	mA
Operating Temperature, To	-40°C to +85°C	С°
Storage Temperature, Ts	-40°C to +100°C	°C

4.0 ELECTRICAL SPECIFICATION

The following parameters apply over the operating temperature range -40° C to $+85^{\circ}$ C and with R_{SS}=10 K-Ohms and V_{DD}= 5V, as per figure A.

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Infra red response		900 nm		1	5	% of peak
Min. operating voltage	$V_{\text{DD}} - V_{\text{adj}}$	lss =250µA		2.0	2.6	V
		lss = 100 μA		1.5	2	V
Adjust Current	I _{ADJ}	200 Lux	150	250	350	μA
		100 Lux	75	125	175	μA
		10 Lux	7.5	12.5	17.5	μA
Adjust Dark Current	ADJ(Dark)	0 Lux, Ta = 25°C		<1	10	nA
		0 Lux, Ta = 85°C		150	200	nA
Gain Linearity			-10		10	%
Peak Spectral Response				520		nm
Sensitive Area				0.054		mm ²
ADJUST Threshold voltage						
for switching of DIG_OUT						
Low to High transition on	V_{LH}	Fading light level		$0.11 \text{xV}_{\text{DD}}$		V
DIG_OUT						
High to Low transition on	V _{HL}	Increasing light level		$0.15 \text{xV}_{\text{DD}}$		V
DIG_OUT						
DIG_OUT Source current	IOUT_SOURCE	$V_{DIG_OUT} = V_{DD} - 0.8V$		24		mA
DIG_OUT Sink current	lout_sink	$V_{DIG_OUT} = 0.8V$		22		mA
Useable light range		R _{SS} & V _{DD} dependant	1	1000		Lux

Note that with a lower Rss resistance connected between the ADJ pin and ground, the linear light response range can be greatly increased. See section 3.1.

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3.1 Selection of Rss

The 413101 can be used over a range of lighting conditions by selecting a suitable value of Rss (see figure A), or by varying Vdd. This table summarises how to select values of Rss. The graph below shows the typical Vadj output response with $1K\Omega$, $10K\Omega$ and $25K\Omega$ resistors. Note that for these examples Vdd is fixed at 5V.

Light Range	413101
0 to 70 Lux	25KΩ
0 to 160 Lux	10KΩ
0 to 600 Lux	1KΩ



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3.2 Characteristic Curves





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4.0 Application Examples

Note:

If the 413101 package has a lens in front of the chip then this will affect the photo sensitivity. The photo sensitivity will also be affected by factors relating to the location of the 413101 in the finished product plastic housings. In some applications the device may sit behind a domed lens which is part of the plastic housing. This lens will increase the photo current and may require a change to the resistor Rss which set the photo sensitivity or switching point. The resistors suggested in the application circuit examples assume that there is no lens on the package and no lens on the housing.

Automatic Night Light



The circuit in Fig 1 shows how the 413101 can be used in a Night Light application.

The power supply to the ASIC is approximately 5VDC. The DIG_OUT pin will be high when the light on the sensor is less than the lower threshold V_{LH} . The DIG_OUT pin will be low when the light on the sensor is higher than the upper threshold V_{HL} .

At the lower threshold V_{LH}: $I_{ADJ} * R1 = 0.1 * V_{DD}$ (1)

At the upper threshold V_{HL}: $I_{ADJ} * R1 = 0.15 * V_{DD}$ (2)

The output source current from the ADJ pin (I_{ADJ}) is approximately 1µA/Lux.

Example.

 V_{DD} = 5V. The light is required to switch ON when illumination at sensor < 20Lux, and switch OFF when illumination at sensor > 30 Lux

With 20 Lux illumination on the sensor $I_{ADJ} = 20\mu A$, Using formula (1) above, R1 = 25K. R3 limits the current flow to the gate of the SCR. This circuit should be suitable for logic SCRs however the gate current should not be too high or it will hold down the V_{DD} supply.

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LED Drivers

Fig 2 shows how the 413101 can be used to drive an LED.



Fig 2

The output of the ASIC switches high and the LED is switched ON when the light level on the sensor generates a voltage on ADJ pin < V_{LH} . R2 limits the base current into TR1. R3 sets the LED current according to the supply voltage. In this circuit, TR1 can be a low cost switching transistor because the 413101 output is a logic signal. The switching thresholds V_{LH} and V_{HL} are controlled by R1.

At the lower threshold V_{LH}: $I_{ADJ} * R1 = 0.1 * V_{DD}$ At the upper threshold V_{HL}: $I_{ADJ} * R1 = 0.15 * V_{DD}$

It is assumed in the following example that $I_{ADJ} = 1\mu A/lux$. This will vary depending on the location and the use of lenses etc.

Example.

 V_{DD} = 5V. The lower threshold will be 30 lux, and the upper threshold will be 45 lux. 30 Lux will provide 30µA at the ADJ pin. 0.1 * V_{DD} = 0.5 30µA * R1 = 0.5 R1 = 16.6K (nearest standard value = 18K)

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Fig 3 In this circuit the LED will switch ON when light on the sensor is higher than V_{HL} and switch off when the light on the sensor is lower than V_{LH} . The PNP transistor TR1 switches ON when the ASIC output is low.





Relay Driver

Fig 4 The 413101 has a push-pull output (DIG_OUT) which switches high when the light is below VLH.



Fig 4

DIG_OUT can source approximately 2mA with a 5V supply. R2 limits the base current into TR1. The switch ON threshold is calculated from

 $I_{ADJ} * R1 = 0.1 * V_{DD}$, where $I_{ADJ} = 1\mu A/Iux$

The switch off threshold is calculated from

 $I_{ADJ} * R1 = 0.15 * V_{DD}$

The max value of IADJ is limited by R1

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Fig 5 In this circuit the relay coil is energised when the DIG_OUT pin of 413101 is low. This will happen when the illumination > V_{HL}





Interface Circuit Examples

Fig 6 is a possible interface to a microprocessor circuit.



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The analogue output from the ADJ pin is connected to an A/D input port of the micro. The voltage across R1 will vary linearly with the light level. Without a lens, the source current from the ADJ pin is approximately 1μ A/Lux so if R1 = 10K, the voltage at the A/D input will vary at 10mV/lux. The analogue port of the micro can then be programmed to read the light level at the sensor. The digital output from the ASIC is connected to a digital input port of the micro, which would allow the port to sense when the light changes between the upper and lower switching thresholds. Typical applications with a microprocessor input could be to control the backlight for the display of a laptop computer or mobile phone.

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Fig 7 The 413101 has a push- pull CMOS digital output which allows it to interface directly to CMOS logic.





The OUT pin is high when the voltage at ADJ < 0.1^*V_{DD} . The OUT pin is low when the voltage at ADJ is > $0.15V_{DD}$.

5.0 Ordering Information

To order the 413101, please use the order codes defined in the following table:

	Options	Ordering Code
Dio Thicknoss	300 µm	G
Die Thickness	525 µm	NG
	+/- 15%	15
Output Current Tolerance	+/- 25%	25
	+/- 40%	40
	Bare die, unsawn wafer	D1
Supply Format	Bare die, sawn wafer	D2
	Surface mount package	S

Examples:

To order sawn wafers, 300 μ m thick, with a tolerance of +/- 40% then use the ordering code: **413101-G-40-D2**.

To order 413101 in a surface mount package with 15% tolerance, use ordering code: **413101-15-S**

Note: Surface mount packaging requires that the wafer be ground down to 300 μm therefore thickness does not need to be specified.

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Semefab (Scotland) Ltd customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Semefab for any damages resulting from such improper use or sale.

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